

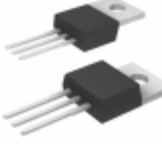







	<h2 style="color: red;">NTP6412ANG</h2>
	<p>Hersteller-Teilenummer: NTP6412ANG</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 58A TO-220AB</p> <p>Datenblätter:  NTP6412ANG.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 33390 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTP6412ANG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 58A TO-220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	33390 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	167W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	58A (Tc)
Rds On (Max) @ Id, Vgs	18.2 mOhm @ 58A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	100nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3500pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube



















































NTP6412ANG ist neu im Original, Suche NTP6412ANG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP6412ANG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP6412ANG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTP6410ANG AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 76A TO-220</p>	 <p>NTP6410AN ON NTP6410AN ON</p>	 <p>NTP6413AN ON NTP6413AN ON</p>	 <p>NTP6412AN ON NTP6412AN ON</p>
 <p>NTP6411AN ON NTP6411AN ON</p>	 <p>NTP65N02R AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 7.6A TO220AB</p>	 <p>NTP6411ANG AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 72A TO-220AB</p>	 <p>NTP6448ANG AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 80A TO-220</p>

heiße Teile

Mehr

 NTP477M04TDR	 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG
 NTP5411NG	 NTP5412NG	 NTP5426N	 NTP5426NG	 NTP5860N
 NTP5860NG	 NTP5860NL	 NTP5860NLG	 NTP5862NG	 NTP5863N
 NTP5863NG	 NTP5864N	 NTP5864NG	 NTP60N06	 NTP60N06G
 NTP60N06L	 NTP60N06LG	 NTP6410AN	 NTP6410ANG	 NTP6411AN
 NTP6411ANG	 NTP6412AN	 NTP6413AN	 NTP6413ANG	 NTP6448ANG
 NTP65N02R	 NTP65N02RG	 NTP75N03-006	 NTP75N03-06	 NTP75N03-06G
 NTP75N03-6G	 NTP75N03L09	 NTP75N03L09G	 NTP75N03R	 NTP75N03RG
 NTP75N06	 NTP75N06D	 NTP75N06G	 NTP75N06L	 NTP85N03G
 NTP85N03RG	 NTP90N02	 NTP90N02G	 NTP90N02R	 NTP90N03

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